50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

1 April 2023

Product data sheet

1. General description

NPN Resistor-Equipped Transistor (RET) in a leadless ultra small SOT883 (SC-101) Surface-Mounted Device (SMD) plastic package.

PNP complement: PDTA143EM

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- · Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	3	
2	GND	ground (emitter)		
3	0	output (collector)		I R1
			1 2	GND R2
			Transparent top view DFN1006-3 (SOT883)	sym007

6. Ordering information

Table 3. Ordering information

Type number	Package	ge				
	Name	Description	Version			
PDTC143EM		plastic, leadless ultra small package; 3 terminals; 0.35 mm pitch; 1 mm x 0.6 mm x 0.48 mm body	<u>SOT883</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code
PDTC143EM	E1

2/12

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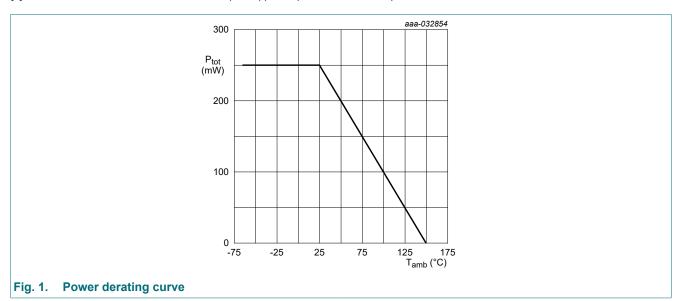
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage			-10	30	V
I _O	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	250	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Reflow soldering is the only recommended soldering method.
- [2] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W

- 1] Reflow soldering is the only recommended soldering method.
- Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

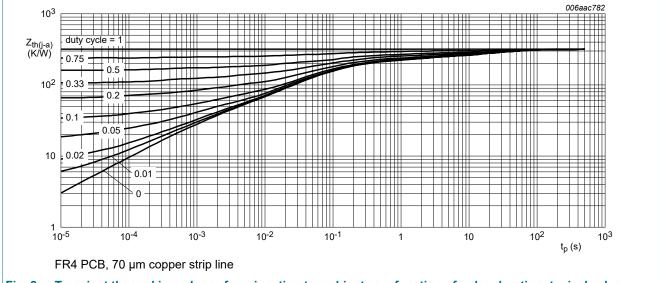


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

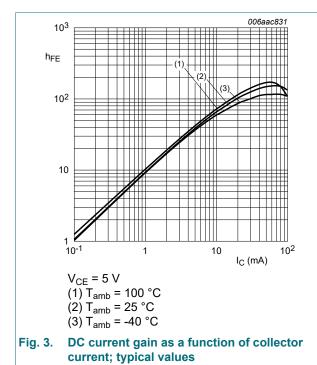
50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

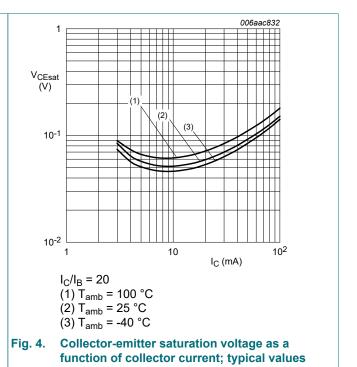
10. Characteristics

Table 7. Characteristics

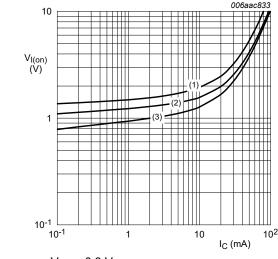
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μΑ
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	900	μΑ
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	1.1	0.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 20 mA; T _{amb} = 25 °C		2.5	1.9	-	V
R1	bias resistor 1 (input)		[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.





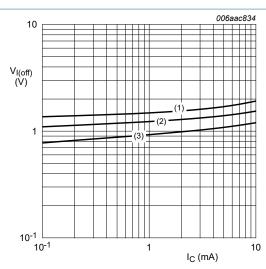
50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω



 $V_{CE} = 0.3 V$

(1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C





V_{CE} = 5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

Off-state input voltage as a function of collector current; typical values

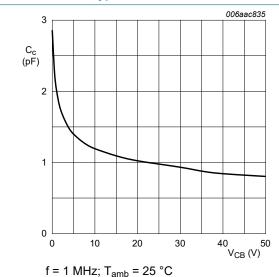
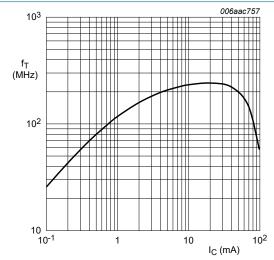


Fig. 7. Collector capacitance as a function of collector- Fig. 8. base voltage; typical values



 V_{CE} = 5 V; T_{amb} = 25 °C

Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

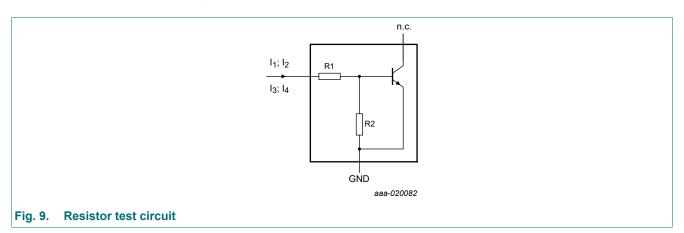
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



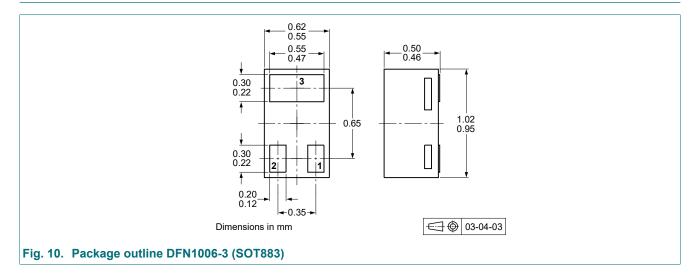
Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	Test conditions				
			I ₁	l ₂	l ₃	14		
PDTC143EM	4.7	4.7	600 µA	700 µA	-600 µA	-700 µA		

50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

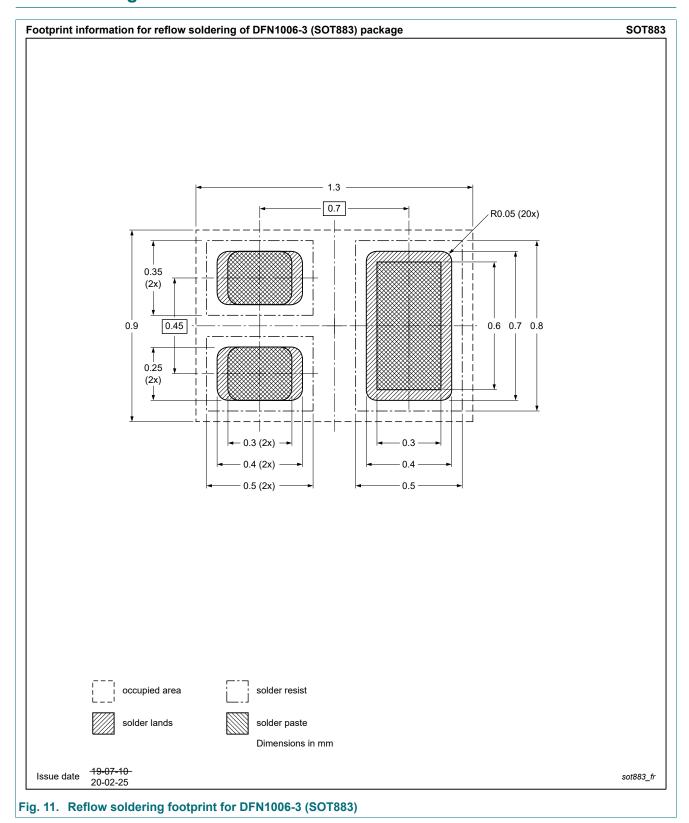
12. Package outline



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50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

13. Soldering



PDTC143EM

50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

14. Revision history

Table 9. Revision history

Release date	Data sheet status	Change notice	Supersedes
20230401	Product data sheet	-	PDTC143E_SERIES v.10
The format of of Nexperia.Legal texts has	this data sheet has been rede ave been adapted to the new o	signed to compl	
20111208	Product data sheet	-	PDTC143E_SERIES v.9
20040805	Product data sheet	-	PDTC143E_SERIES v.8
20040318	Product specification	-	PDTC143E_SERIES v.7
20040112	Product specification	-	PDTC143E_SERIES v.6
20030910	Product specification	-	PDTC143E_SERIES v.5
20030410	Product specification	-	-
	20230401 Family data s The format of of Nexperia. Legal texts ha Packing information of the process of the	 Product data sheet Family data sheet reduced to single type data. The format of this data sheet has been reder of Nexperia. Legal texts have been adapted to the new of Packing information removed. Product data sheet Product data sheet Product specification Product specification Product specification Product specification Product specification Product specification 	Product data sheet - Family data sheet reduced to single type data sheet. The format of this data sheet has been redesigned to compl of Nexperia. Legal texts have been adapted to the new company name we Packing information removed. Product data sheet - 20040805 Product data sheet - 20040318 Product specification - 20040112 Product specification - 20030910 Product specification -

50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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50 V, 100 mA NPN resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 4.7 k Ω

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